

Features

- Epitaxial Planar Die Construction
- Complementary PNP Types Available (DDTB)
- Built-In Biasing Resistors
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**

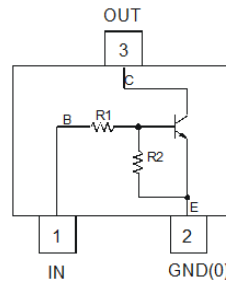
Mechanical Data

- Case: SOT-23
- Case Material: Molded Plastic, "Green" Molding Compound; UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish – Matte Tin Plated Leads; Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.008 grams (Approximate)

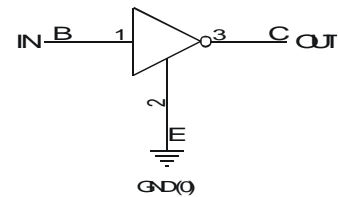
P/N	R1 (NOM)	R2 (NOM)
DDTD122LC	0.22kΩ	10kΩ
DDTD142JC	0.47kΩ	10kΩ
DDTD122TC	0.22kΩ	OPEN
DDTD142TC	0.47kΩ	OPEN



Top View



Device Schematic



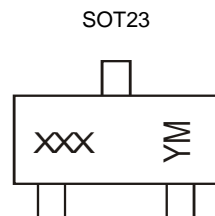
Equivalent Inverter Circuit

Ordering Information (Note 4)

Product	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
DDTD122LC -7-F	AEC-Q101	N75	7	8	3,000
DDTD142JC -7-F	AEC-Q101	N76	7	8	3,000
DDTD122TC -7-F	AEC-Q101	N77	7	8	3,000
DDTD142TC -7-F	AEC-Q101	N78	7	8	3,000

- Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
 4. For packaging details, go to our website at <http://www.diodes.com/products/packages.html>.

Marking Information



XXX = Product Type Marking Code, See Table Above
 YM = Date Code Marking
 Y = Year ex: B = 2014
 M = Month ex: 9 = September

Date Code Key

Year	2014	2015	2016	2017	2018	2019	2020	2021	2022
Code	B	C	D	E	F	G	H	I	J

Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D

Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Supply Voltage <Pin: (3) to (2)>	V _{CC}	50	V
Input Voltage <Pin: (1) to (2)>	V _{IN}	-5 to +6	V
Input Voltage <Pin: (2) to (1)>	V _{EBO (MAX)}	5	V
Output Current	I _C	500	mA

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	P _D	200	mW
Thermal Resistance, Junction to Ambient Air (Note 5)	R _{θJA}	625	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

Note: 5. Mounted on FR4 PC board with recommended pad layout.

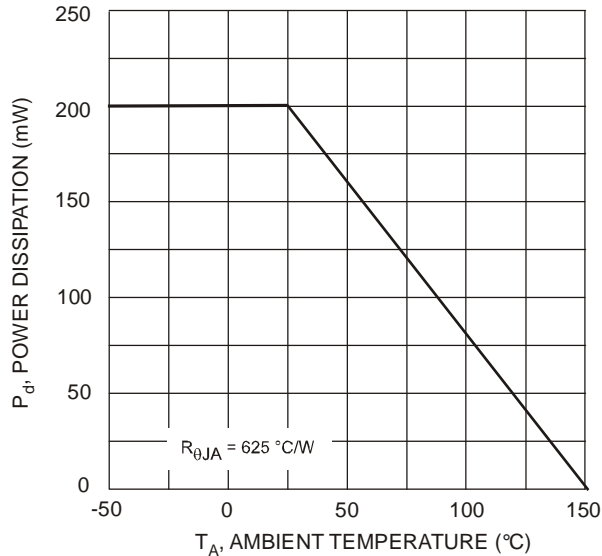


Fig. 1 Power Derating Curve

Electrical Characteristics - R1, R2 Types (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Min	Typ	Max	Unit	Test Condition
Input Voltage	DDTD122LC DDTD142JC	V _{I(off)}	0.3 0.3	—	—	V	V _{CC} = 5V, I _O = 100μA
	DDTD122LC DDTD142JC	V _{I(on)}	—	—	2.0 2.0	V	V _O = 0.3V, I _O = 20mA V _O = 0.3V, I _O = 20mA
Output Voltage		V _{O(on)}	—	—	0.3V	V	I _O /I _I = 50mA/2.5mA
Input Current	DDTD122LC DDTD142JC	I _I	—	—	28 13	mA	V _I = 5V
Output Current		I _{O(off)}	—	—	0.5	μA	V _{CC} = 50V, V _I = 0V
DC Current Gain	DDTD122LC DDTD142JC	G _I	56 56	—	—	—	V _O = 5V, I _O = 50mA
Gain-Bandwidth Product (Note 6)		f _T	—	200	—	MHz	V _{CE} = 10V, I _E = 5mA, f = 100MHz

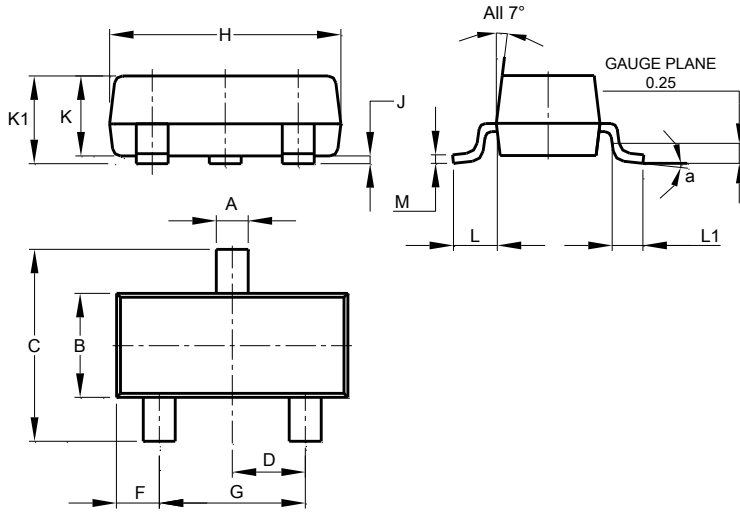
Electrical Characteristics - R1- Only, R2- Only Types (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage		BV _{CB0}	50	—	—	V	I _C = 50μA
Collector-Emitter Breakdown Voltage		BV _{CEO}	40	—	—	V	I _C = 1mA
Emitter-Base Breakdown Voltage	DDTD122TC DDTD142TC	BV _{EBO}	5	—	—	V	I _E = 50μA I _E = 50μA
Collector Cut-Off Current		I _{CB0}	—	—	0.5	μA	V _{CB} = 50V
Emitter Cut-Off Current	DDTD122TC DDTD142TC	I _{EBO}	— —	—	0.5 0.5	μA	V _{EB} = 4V
Collector-Emitter Saturation Voltage		V _{CE(sat)}	—	—	0.3	V	I _C = 50mA, I _B = 2.5mA
DC Current Transfer Ratio	DDTD122TC DDTD142TC	h _{FE}	100 100	250 250	600 600	—	I _C = 5mA, V _{CE} = 5V
Gain-Bandwidth Product (Note 6)		f _T	—	200	—	MHz	V _{CE} = 10V, I _E = -5mA, f = 100MHz

Note: 6. Transistor – For Reference Only

Package Outline Dimensions

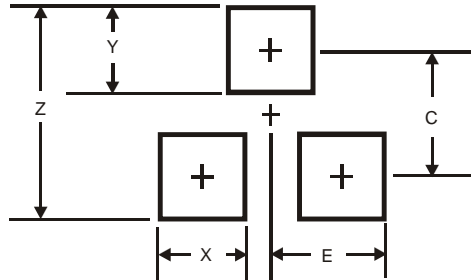
Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for the latest version.



SOT23			
Dim	Min	Max	Typ
A	0.37	0.51	0.40
B	1.20	1.40	1.30
C	2.30	2.50	2.40
D	0.89	1.03	0.915
F	0.45	0.60	0.535
G	1.78	2.05	1.83
H	2.80	3.00	2.90
J	0.013	0.10	0.05
K	0.890	1.00	0.975
K1	0.903	1.10	1.025
L	0.45	0.61	0.55
L1	0.25	0.55	0.40
M	0.085	0.150	0.110
a	8°		
All Dimensions in mm			

Suggested Pad Layout

Please see AP02001 at <http://www.diodes.com/datasheets/ap02001.pdf> for the latest version.



Dimensions	Value (in mm)
Z	2.9
X	0.8
Y	0.9
C	2.0
E	1.35

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